

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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| In re Patent Application of |) | |
| |) | |
| Shibly S. Ahmed et al. |) | |
| |) | |
| Application No.: Unassigned |) | Group Art Unit: Unassigned |
| Continuation Application of 10/310,777 |) | |
| |) | |
| Filed: November 25, 2003 |) | Examiner: Unassigned |
| |) | |
| For: DOUBLE GATE SEMICONDUCTOR |) | |
| DEVICE HAVING A METAL GATE |) | |
| (AS AMENDED) |) | |

PRELIMINARY AMENDMENT

U.S. Patent and Trademark Office
2011 South Clark Place
Customer Window, Mail Stop Non-Fee Amendment
Crystal Plaza Two, Lobby, Room 1B03
Arlington, VA 22202

Sir:

Prior to examination, please amend this application as follows.

Amendments to the Title begin on page 2 of this paper.

Amendments to the Specification begin on page 3 of this paper.

Amendments to the Claims begin on page 5 of this paper.

Amendments to the Abstract begin on page 10 of this paper.

Remarks begin on page 11 of this paper.

Amendments to the Title:

Please replace the title with the following rewritten title:

~~DAMASCENE GATE PROCESS WITH SACRIFICIAL OXIDE IN~~
~~SEMICONDUCTOR DEVICES~~ DOUBLE GATE SEMICONDUCTOR DEVICE
HAVING A METAL GATE